

2SK1920

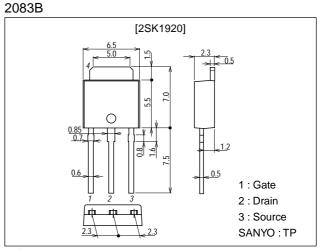
Ultrahigh-Speed Switching Applications

Features

- · Low ON resistance.
- · Ultrahigh-speed switching.
- · Low-voltage drive.

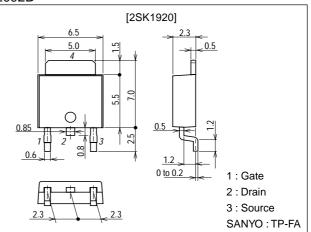
Package Dimensions

unit:mm



unit:mm

2092B



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Specifications

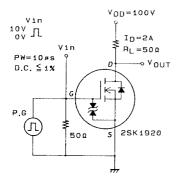
Absolute Maximum Ratings at Ta = 25°C

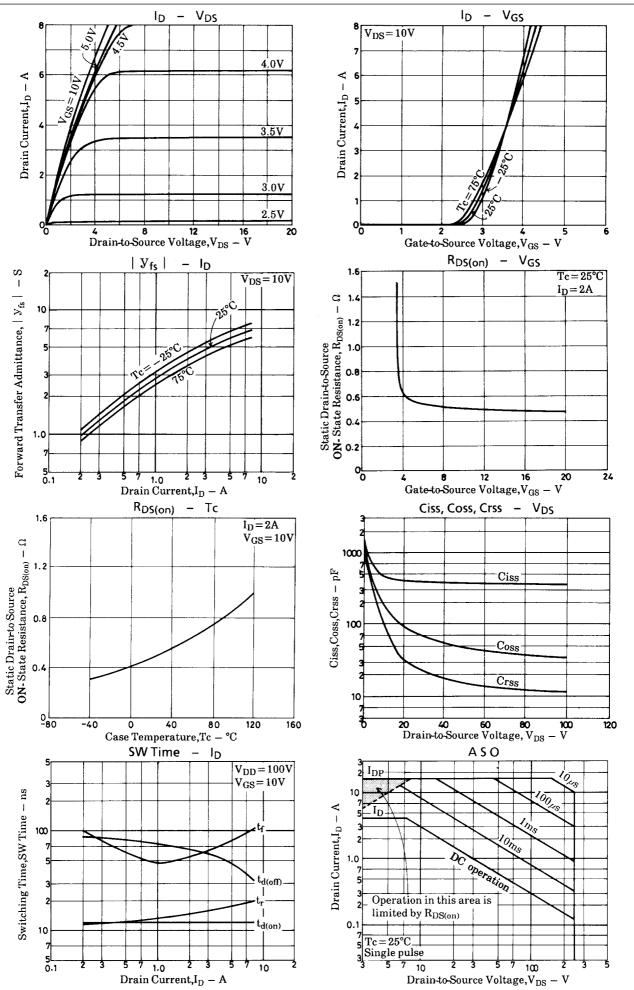
Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V _{DSS}		250	V
Gate-to-Source Voltage	V _{GSS}		±30	V
Drain Current (DC)	۱ _D		4	A
Drain Current (pulse)	IDP	PW≤10µs, duty cycle≤1%	16	A
Allowable Power Dissipation	PD		1.0	W
	F D	Tc=25°C	30	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

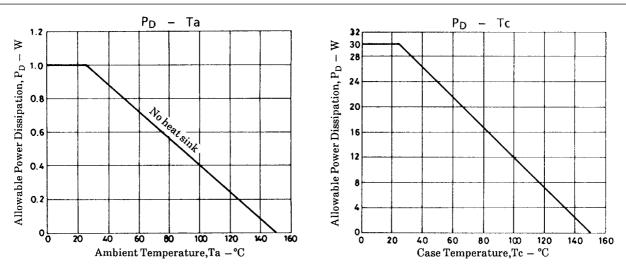
Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			1.1 14
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _{GS} =0	250			V
Gate-to-Source Breakdown Voltage	V(BR)GSS	I _G =±100μA, V _{DS} =0	±30			V
Zero-Gate Votlage Drain Current	IDSS	V _{DS} =250V, V _{GS} =0			100	μA
Gate-to-Source Leakage Current	IGSS	V _{GS} =±25V, V _{DS} =0			±10	μA
Cutoff Voltage	V _{GS(off)}	V _{DS} =10V, I _D =1mA	1.5		2.5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =2A	2.5	4		S
Static Drain-to-Source On-State Resistance	R _{DS(on)}	ID=2A, VGS=10V		500	700	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		420		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		95		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		30		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit		12		ns
Rise Time	tr	See specified Test Circuit		15		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit		65		ns
Fall Time	tf	See specified Test Circuit		55		ns
Diode Forward Voltage	V _{SD}	IS=4A, VGS=0		1.0	1.5	V

Switching Time Test Circuit







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